NSN 5961-01-406-7540

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-406-7540 **Inclosure Material:** Metal **Electrode Internally-electrically Connected To Case:** Cathode **Mounting Method:** Threaded stud **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 200.0 reverse voltage, instantaneous **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius case **Terminal Type And Quantity:** 1 tab, solder lug and 1 case Shelf Life: N/a **Unit Of Measure:** Demilitarization: No

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